



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



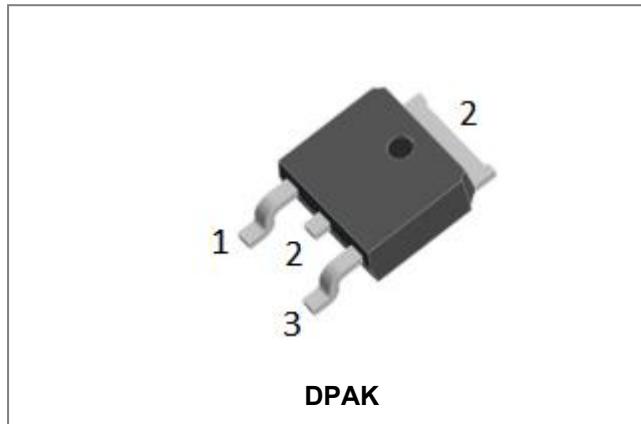
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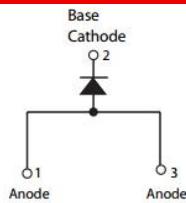
MBRD660 SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- “-A” is an AEC-Q101 qualified device
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Disk drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|---|------------|---|------|-------|
| Peak Repetitive Reverse Voltage | V_{RRM} | - | | |
| Working Peak Reverse Voltage | V_{RWM} | | 60 | V |
| DC Blocking Voltage | V_R | | | |
| Average Rectified Forward Current | $I_F (AV)$ | 50% duty cycle @ $T_c=85^\circ\text{C}$, rectangular wave form | 6 | A |
| Peak One Cycle Non-Repetitive Surge Current | I_{FSM} | 8.3ms, Half Sine pulse | 125 | A |

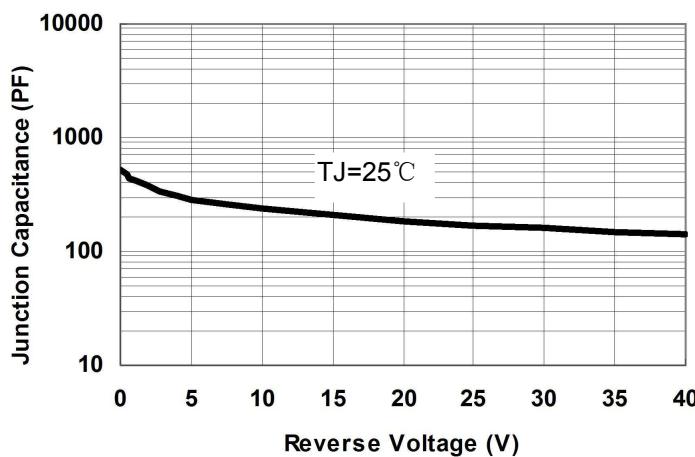
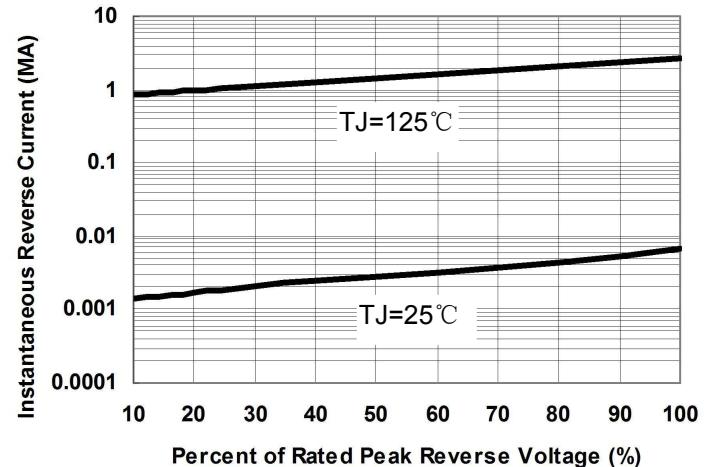
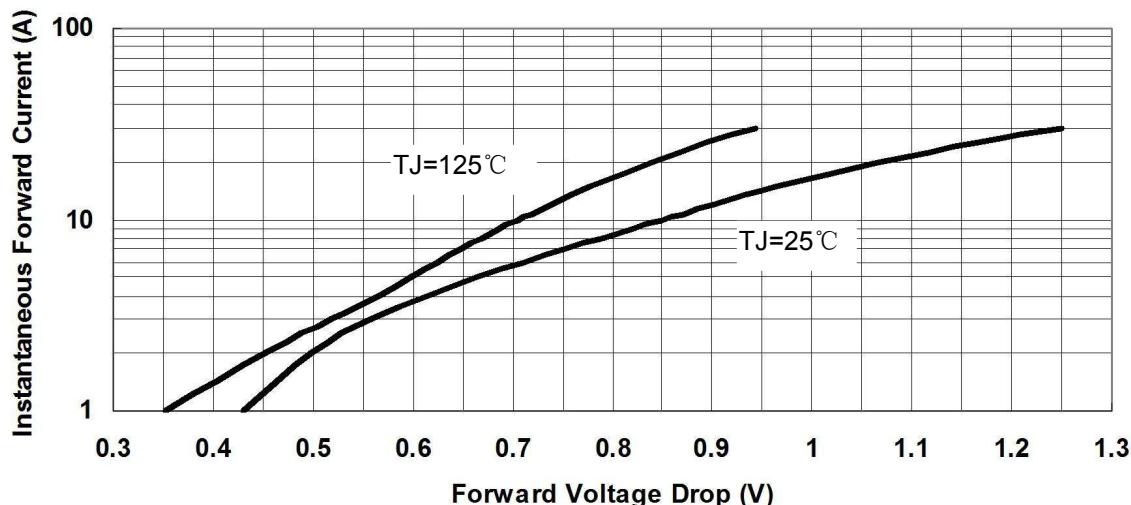
Electrical Characteristics:

| Characteristics | Symbol | Condition | Typ. | Max. | Units |
|------------------------|----------|---|------|--------|------------------|
| Forward Voltage Drop* | V_{F1} | @ 6A, Pulse, $T_J = 25^\circ\text{C}$ | 0.70 | 0.75 | V |
| | V_{F2} | @ 6A, Pulse, $T_J = 125^\circ\text{C}$ | 0.60 | 0.70 | V |
| Reverse Current * | I_{R1} | @ V_R = rated V_R , $T_J = 25^\circ\text{C}$ | 0.01 | 1 | mA |
| | I_{R2} | @ V_R = rated V_R , $T_J = 125^\circ\text{C}$ | 3 | 10 | mA |
| Junction Capacitance | C_T | @ $V_R = 5.0\text{V}$, $T_c = 25^\circ\text{C}$ $f_{SIG} = 1\text{MHz}$ | 300 | 400 | pF |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/ μs |

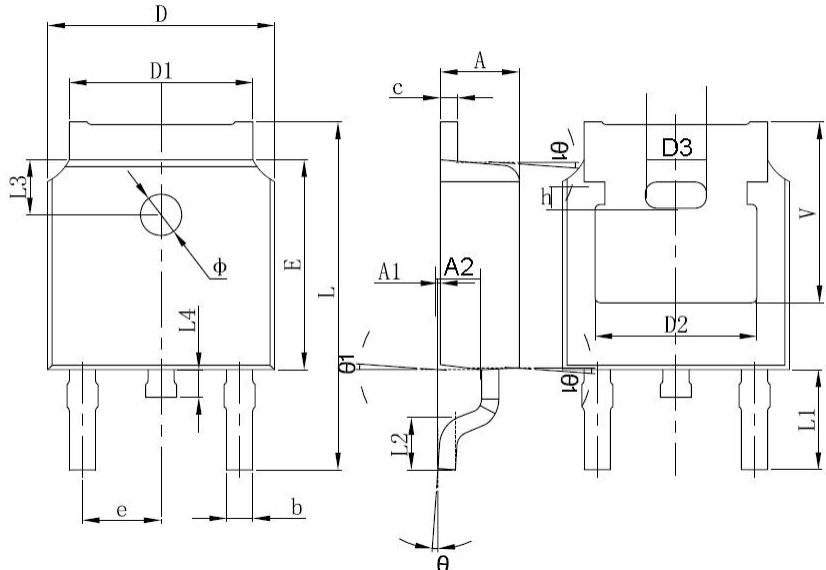
* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|-----------------|-----------|---------------|-------|
| Junction Temperature | T_J | - | -55 to +150 | °C |
| Storage Temperature | T_{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Case | $R_{\theta JC}$ | - | 6 | °C/W |
| Approximate Weight | w_t | - | 0.39 | g |
| Case Style | | | DPAK | |

Ratings and Characteristics Curves

Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

Fig.3-Typical Instantaneous Forward Voltage Characteristics

- China - Germany - Korea - Singapore - United States •
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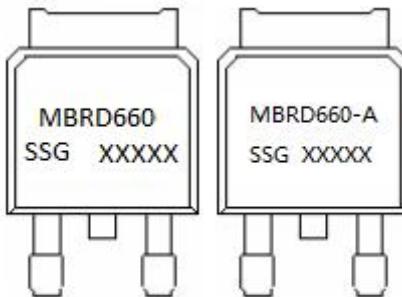
Mechanical Dimensions DPAK


| SYMBOL | Millimeters | | Inches | |
|--------|-------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 2.20 | 2.40 | 0.087 | 0.094 |
| A1 | 0.00 | 0.127 | 0.000 | 0.005 |
| b | 0.66 | 0.86 | 0.026 | 0.034 |
| c | 0.46 | 0.60 | 0.018 | 0.024 |
| D | 6.50 | 6.70 | 0.256 | 0.264 |
| D1 | 5.13 | 5.46 | 0.202 | 0.215 |
| D2 | 4.83 | REF. | 0.190 | REF. |
| E | 6.00 | 6.20 | 0.236 | 0.244 |
| e | 2.186 | 2.386 | 0.086 | 0.094 |
| L | 9.70 | 10.40 | 0.381 | 0.409 |
| L1 | 2.90 | REF. | 0.144 | REF. |
| L2 | 1.40 | 1.70 | 0.055 | 0.067 |
| L3 | 1.60 | REF. | 0.063 | REF. |
| L4 | 0.60 | 1.00 | 0.024 | 0.039 |
| Φ | 1.10 | 1.30 | 0.043 | 0.051 |
| Θ | 0° | 8° | 0° | 8° |
| h | 0.00 | 0.30 | 0.000 | 0.012 |
| V | 5.35 | REF. | 0.211 | REF. |

Ordering Information

| Device | Package | Shipping |
|---------|----------------|----------------|
| MBRD660 | DPAK (Pb-Free) | 2500pcs / reel |

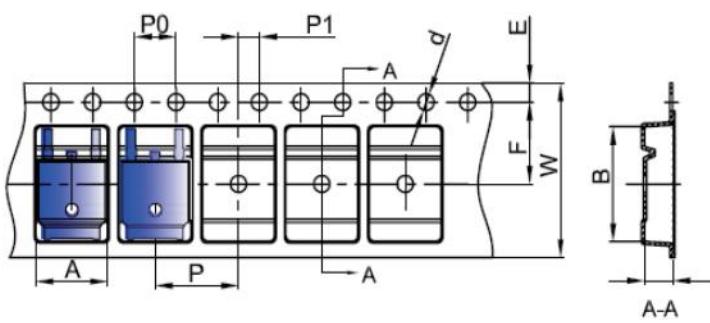
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram


Where XXXXX is YYWWL

MBRD660 = Part Name
 -A = AEC-Q101
 SSG = SSG
 YY = Year
 WW = Week
 L = Lot Number

Cautions: Molding resin
 Epoxy resin UL:94V-0

Carrier Tape & Reel Specification DPAK


| SYMBOL | Millimeters | |
|--------|-------------|-------|
| | Min. | Max. |
| A | 6.80 | 7.00 |
| B | 10.40 | 10.60 |
| C | 2.60 | 2.80 |
| d | Φ1.45 | Φ1.65 |
| E | 1.65 | 1.85 |
| F | 7.40 | 7.60 |
| P0 | 3.90 | 4.10 |
| P | 7.90 | 8.10 |
| P1 | 1.90 | 2.10 |
| W | 15.90 | 16.30 |

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